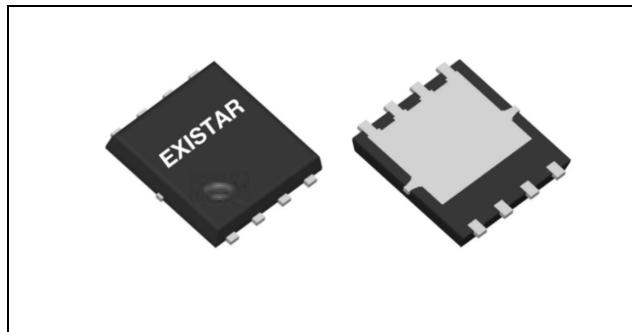


N-Channel 60V MOSFET

E060N8P5HL1

V _{DS} (V)	R _{DS(on),typ} (mΩ)	I _D (A)
60V	8.5@ V _{GS} = 10V	64

PDFN5X6

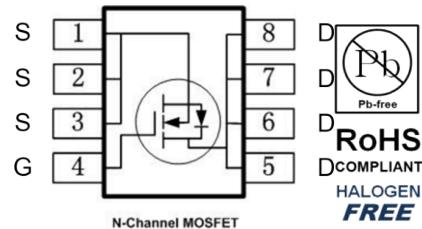


Features

- Low R_{DS(on)} trench technology
- Low thermal impedance
- Fast switching speed
- 100% avalanche tested

Applications

- DC/DC conversion
- Power switch
- PD charger
- Moto driver



Package And Ordering Information

Ordering code	Package	Marking
E060N8P5HL1	PDFN5X6	E060N8P5HL1

Ordering Information

Package	Units/ Reel	Reels/ Inner Box	Units/ Inner Box
PDFN5X6	5000	1	5000

Key Performance Parameters

Parameter	Value	Unit
VDS, min @ Tj(max)	60	V
ID, pulse	256	A
RDS(ON), max @ VGS=10V	9.5	mΩ
Qg	12	nC

Absolute Maximum Ratings at Tj=25°C Unless Otherwise Noted

Parameter	Symbol	Limit	Unit
Drain-source voltage	V _{DS}	60	V
Gate-source voltage	V _{GS}	±20	
Continuous drain current	T _C =25°C	I _D	
	T _C =100°C	-	
Pulsed drain current	I _{D,pulse}	256	A
Avalanche energy, single pulse	E _{AS}	18	mJ
Power dissipation	T _C =25°C	P _D	W
	T _A =25°C	-	
Operating junction and storage temperature range	T _J , T _{stg}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Max.	Unit
Thermal resistance, junction-to-case	R _{θJC}	2	°C/W
Thermal resistance, junction-to-ambient	R _{θJA}	62	

Electrical Characteristics at Tj=25°C unless otherwise specified

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Static						
Drain to source breakdown voltage	V _{(BR)DSS}	60			V	V _{GS} = 0, I _D = 250 μA
Gate-source threshold voltage	V _{GS(th)}	1.0		2.2	V	V _{DS} = V _{GS} , I _D = 250 μA
Gate-body leakage	I _{GSS}			±100	nA	V _{DS} = 0 V, V _{GS} = ±20 V
Zero gate voltage drain current	I _{DSS}			1	μA	V _{DS} = 60 V, V _{GS} = 0 V
Drain-source on-resistance	R _{Ds(on)}		8.5	9.5	mΩ	V _{GS} = 10 V, I _D = 12 A
Drain-source on-resistance	R _{Ds(on)}		10.7	12.5	mΩ	V _{GS} = 4.5 V, I _D = 9 A

Forward transconductance	g_{fs}		-		S	$V_{DS} = 5 \text{ V}, I_D = 20 \text{ A}$
Gate resistance	R_g		1.95		Ω	$f=1\text{MHz}$
Gate Charge						
Total gate charge	Q_g		12		nC	$V_{DS} = 30 \text{ V}, I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}$
Gate-source charge	Q_{gs}		3			
Gate-drain charge	Q_{gd}		2.2			
Dynamic						
Turn-on delay time	$t_{d(on)}$		15		ns	$V_{DS} = 30 \text{ V}, I_D = 25 \text{ A}, V_{GS} = 10 \text{ V}, R_{GEN} = 2 \Omega$
Rise time	t_r		3			
Turn-off delay time	$t_{d(off)}$		28.2			
Fall time	t_f		3.1		pF	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1\text{MHz}$
Input capacitance	C_{iss}		1040			
Output capacitance	C_{oss}		362			
Reverse transfer capacitance	C_{rss}		26.5			
Body Diode						
Diode forward voltage	V_{SD}			1.3	V	$V_{GS} = 0 \text{ V}, I_F = 20 \text{ A}$
Reverse recovery time	t_{rr}		36.2		ns	$V_R = 30 \text{ V}, I_S = 25 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}$
Reverse recovery charge	Q_{rr}		18.6		nC	

Electrical Characteristics Diagrams

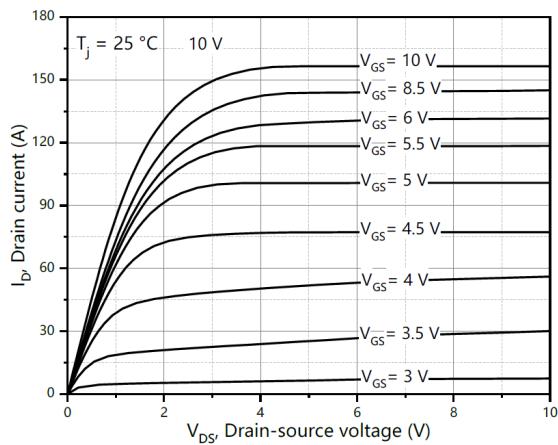


Figure 1. Typ. output characteristics

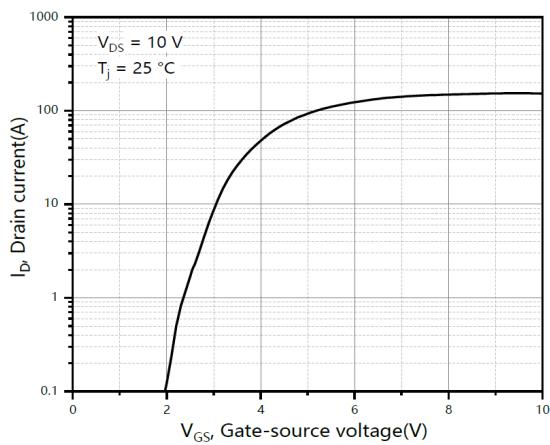


Figure 2. Typ. transfer characteristics

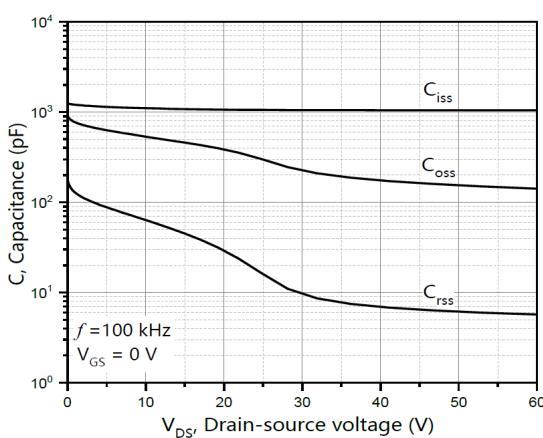


Figure 3. Typ. capacitances

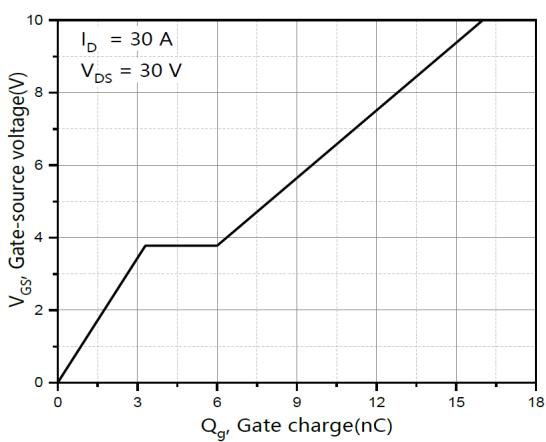


Figure 4. Typ. gate charge

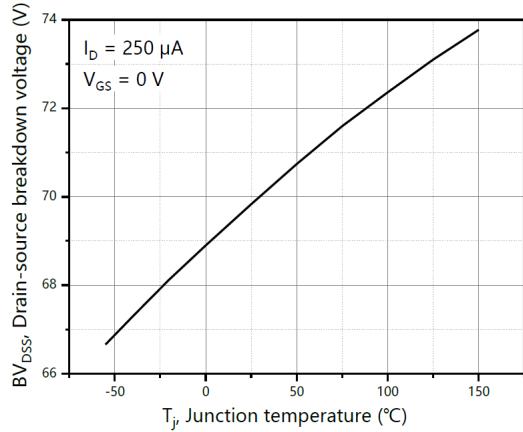


Figure 5. Drain-source breakdown voltage

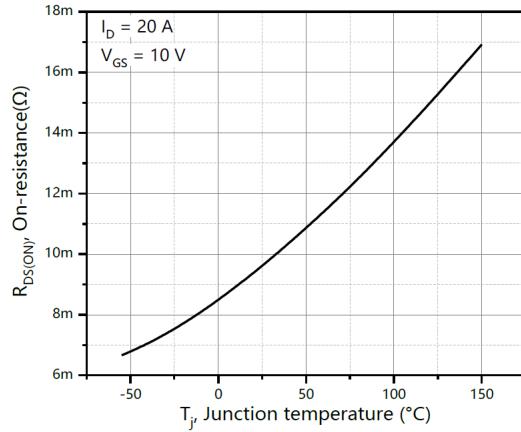


Figure 6. Drain-source on-state resistance

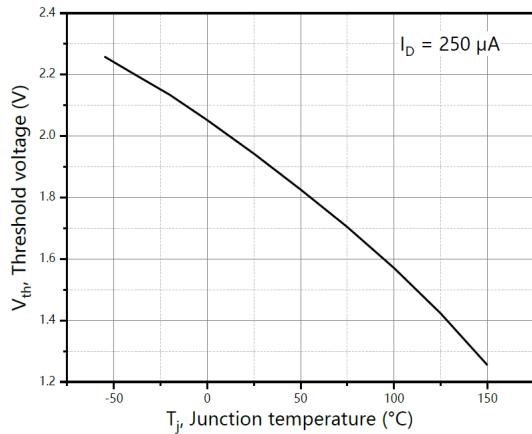


Figure 7. Threshold voltage

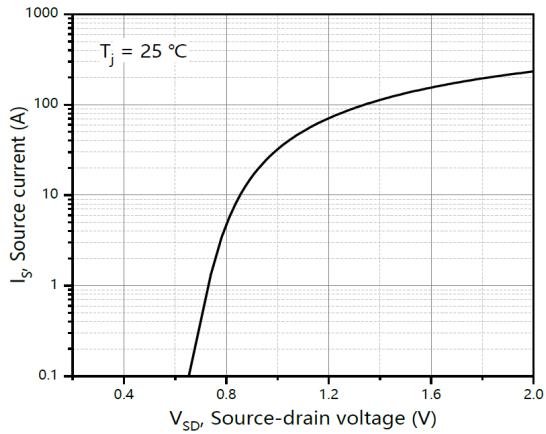


Figure 8. Forward characteristic of body diode

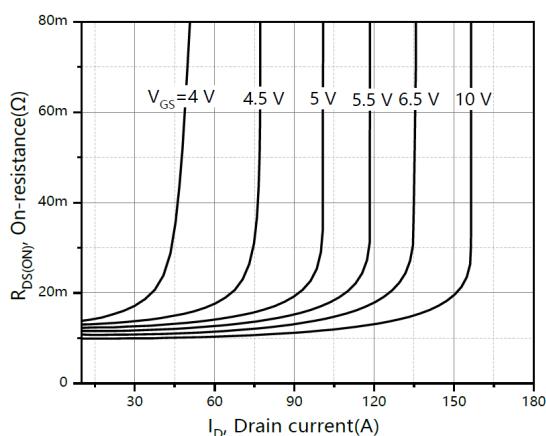


Figure 9. Drain-source on-state resistance

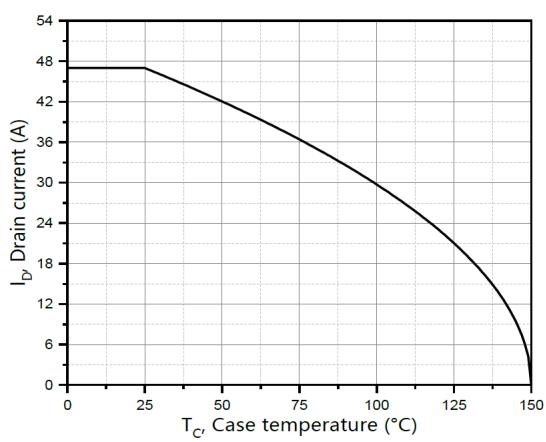


Figure 10. Drain current

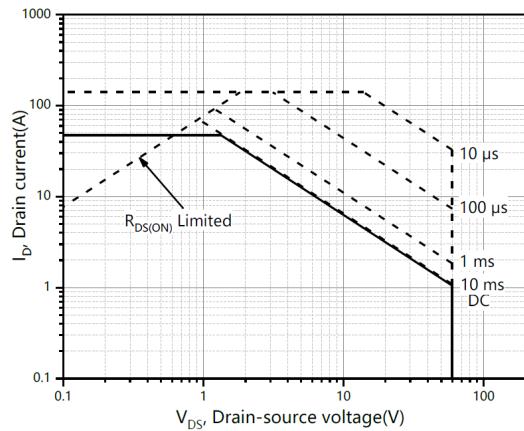


Figure 11. Safe operation area $T_c=25$ °C

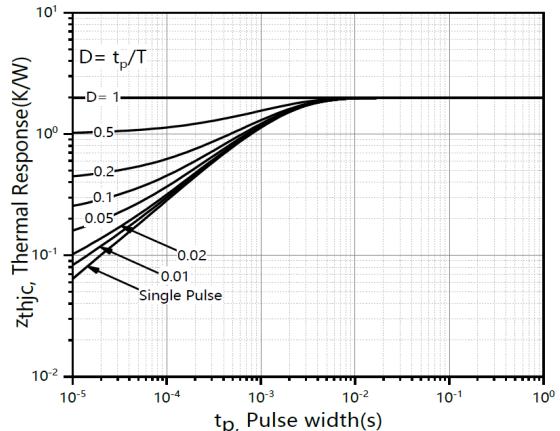


Figure 12. Max. transient thermal impedance

Test circuits and waveforms

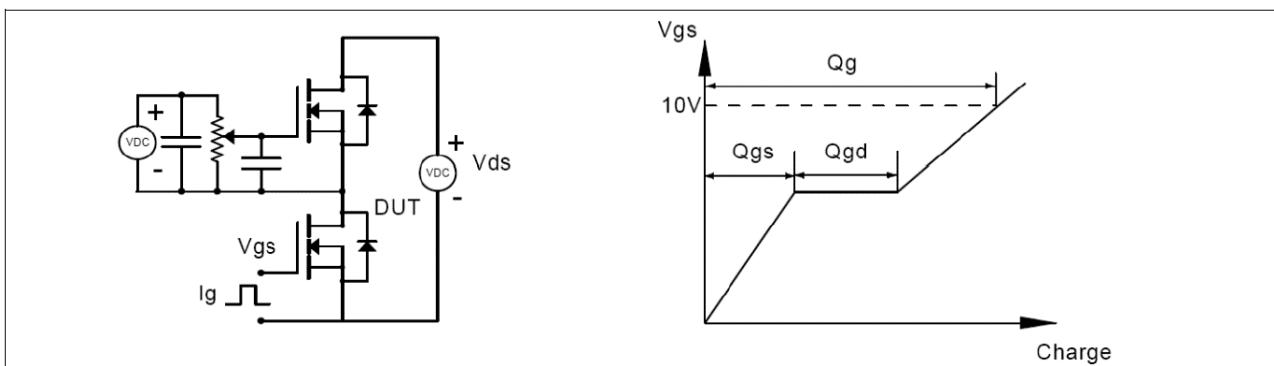


Figure 1. Gate charge test circuit & waveform

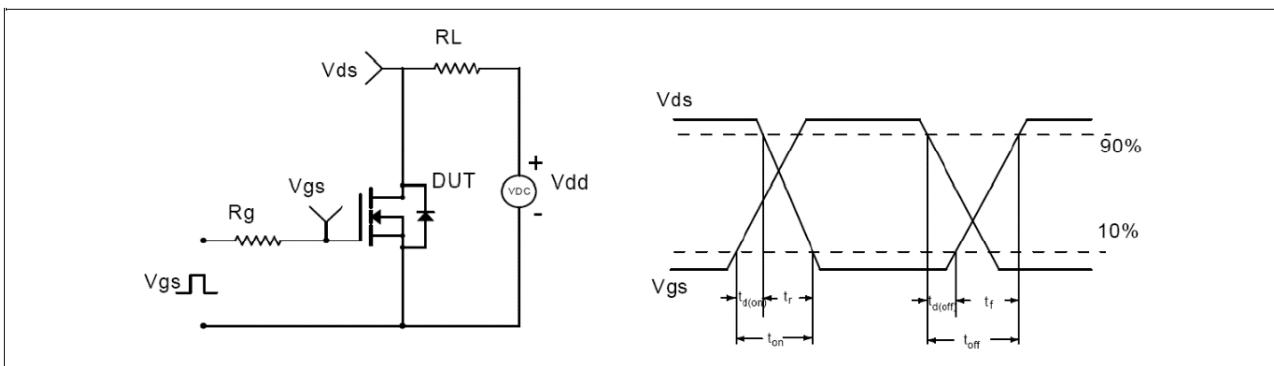


Figure 2. Switching time test circuit & waveforms

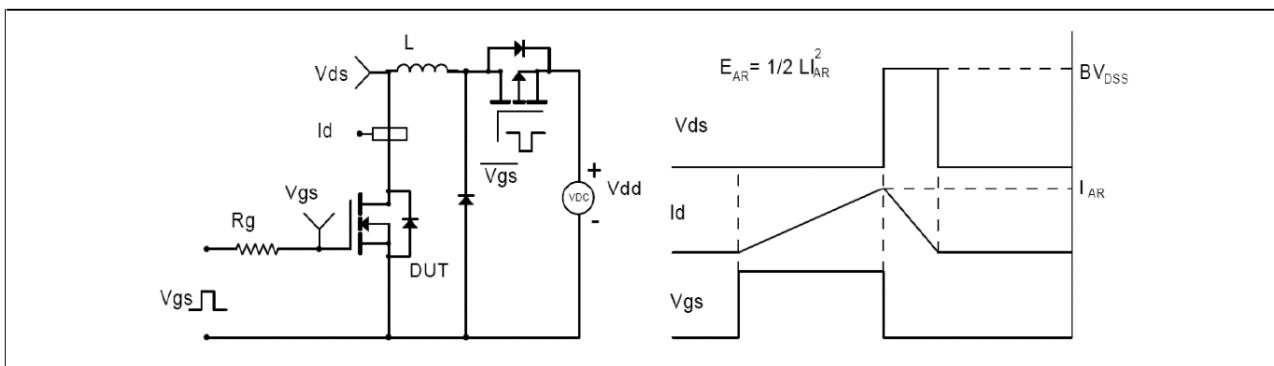


Figure 3. Unclamped inductive switching (UIS) test circuit & waveforms

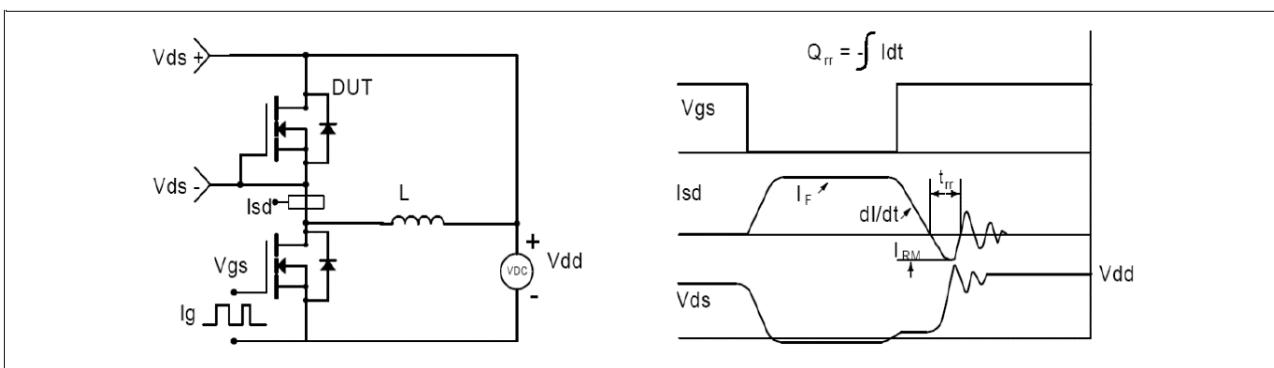
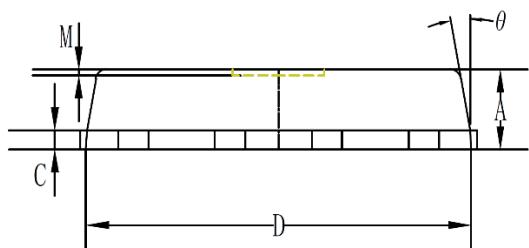
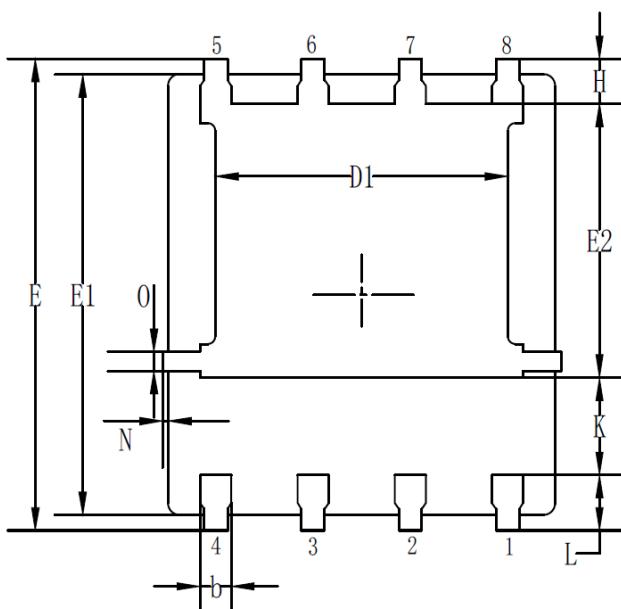
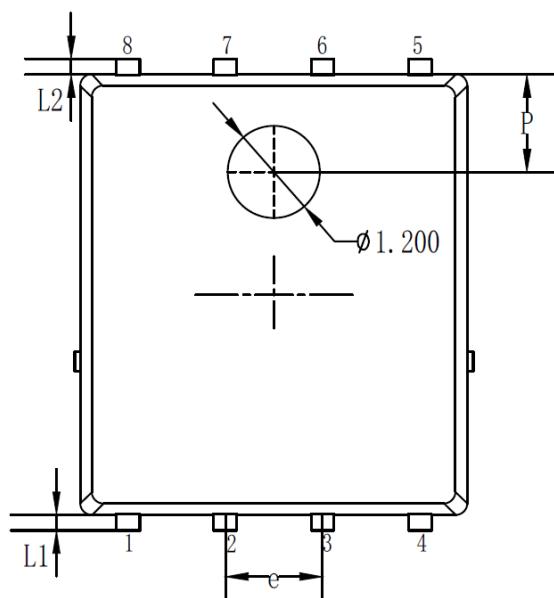


Figure 4. Diode reverse recovery test circuit & waveforms

Package Outline Dimensions


Symbols	Millimeters		
	MIN.	NOM.	MAX.
A	0.90	1.05	1.20
b	0.35	0.40	0.50
C	0.20	0.25	0.35
D	4.90	5.05	5.20
D1	3.72	3.82	3.92
E	0.60	6.15	6.30
E1	5.60	5.75	5.90
E2	3.47	3.57	3.67
e	1.27 BSC.		
H	0.48	0.58	0.68
K	1.17	1.27	1.37
L	0.64	0.74	0.84
L1/L2	0.20 REF.		
θ	8°	10°	12°
M	0.08 REF.		
N	0	-	0.15
O	0.25 REF.		
P	1.28 REF.		

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